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Chasing the spin gap through the phase diagram of a frustrated Mott insulator

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The quest for entangled spin excitations has stimulated intense research on frustrated magnetic systems. For almost two decades, the triangular-lattice Mott insulator κ -(BEDT-TTF)₂Cu₂(CN)₃ has been the hottest candidate for a *gapless* quantum spin liquid with itinerant spinons. Very recently, however, this scenario was overturned as electron-spin-resonance (ESR) studies unveiled a spin gap, calling for reevaluation of the magnetic ground state. Here we achieve a precise mapping of this spin-gapped phase through the Mott transition by ultrahigh-resolution strain tuning. Our transport experiments reveal a reentrance of charge localization below $T^* = 6$ K associated with a gap size of 30–50 K. The negative slope of the insulator-metal boundary, $dT^*/dp < 0$, evidences the low-entropy nature of the spin-singlet ground state. By tuning the enigmatic '6K anomaly' through the phase diagram of κ -(BEDT-TTF)₂Cu₂(CN)₃, we identify it as the transition to a valence-bond-solid phase, with typical magnetic and structural fingerprints, that persists at $T \to 0$ until unconventional superconductivity and metallic transport proliferate.

Since Anderson's notion of resonating valence bonds,¹ the quest for quantum spin liquids (QSL) has been fueled by the idea that suppressing long-range antiferromagnetic (AFM) order can stabilize itinerant or even topological spin excitations.^{2,3} What is often neglected is that the coupling of magnetic degrees of freedom to the lattice can result in valence-bond-solid (VBS) phases with paired electron spins. Such singlet states occur, for instance, in triangular-lattice organic compounds,^{4–8} and in form of the well-known spin-Peierls (SP) states in quasi 1D systems.^{9,10} Also in other frustrated materials the importance of valence-bond phases has been revived.^{11–14} Such a VBS scenario is fully consistent with the report of a spin gap in the organic QSL candidate κ -(BEDT- $TTF)_2Cu_2(CN)_3$ that aroused great attention in the QSL community very recently.^{15,16} While this finding rules out the widely assumed scenario of mobile spinons,¹⁷ in agreement with thermal transport results,¹⁸ it leaves open the possibility of gapped QSL phases.³

The tunability of κ -(BEDT-TTF)₂Cu₂(CN)₃ – a pressure of 1.3 kbar triggers the transition from a Mott insulator to superconducting (SC) and metallic phases^{5,6,21–24} as illustrated in Fig. 1d – provides the unique opportunity to scrutinize the entropy of its magnetic ground state. According to the Clausius-Clapeyron relation, the pressure-tuned metal-insulator transition (MIT) acquires a positive slope $dT_{\rm MI}/dp > 0$ in the T-p phase diagram between a paramagnetic Mott insulator with large spin entropy and a metal (Fig. 1b), reminiscent of the Pomeranchuk effect in ³He.²⁴ On the other hand, the entropy of AFM and VBS states is smaller than that of the Fermiliquid (FL) metal, yielding negative slopes $dT_{\rm N}/dp < 0$ and $dT^*/dp < 0$ of the MIT (Fig. 1a,c), respectively.

Here we utilize the slope of the insulator-metal boundary of κ -(BEDT-TTF)₂Cu₂(CN)₃ as a probe of the spingapped ground state below $T^* = 6$ K, evidencing its lowentropy nature. For that, we map the low-temperature Mott MIT with ultrahigh precision by measuring dc transport upon a combination of biaxial compression and tensile strain. We find a reentrance of insulating behavior setting in below T^* , which is successively suppressed as metallicity proliferates. Through comparison with previously reported structural^{7,25} and magnetic¹⁵ properties, our present results clearly identify the '6K anomaly' as the transition to a VBS phase with $dT^*/dp < 0$ (Fig. 1c) and, thus, we complete the phase diagram of κ -(BEDT--TTF)₂Cu₂(CN)₃. Moreover, our transport data yield a gap size of 30–50 K for the spin-singlet state, which coincides with the unexpectedly large critical field of 60 T.¹⁶

Among the QSL candidates, κ -(BEDT-TTF)₂- $Cu_2(CN)_3$ has been studied most intensely as it exhibits not only frustrated AFM exchange interactions $(J = 250 \text{ K}^{26})$, but also a paradigmatic Mott transition.^{21,24,27} This layered triangular-lattice compound with t'/t close to unity shows no AFM order²⁶ and, at the same time, it is one of the best solid-state realizations of the single-band Hubbard model.²⁴ As such, it provides experimental access to check the predictions of dynamical mean-field theory: while the Mott transition is first-order type below the critical endpoint T_{crit} , a quantum-critical crossover at the quantum Widom line (QWL) occurs at $T > T_{crit}$.^{24,27–29} Moreover, applying 1–2 kbar pressure allows to probe unconventional $\mathrm{SC}^{21,23}$ as well as charge transport in Fermi liquids and bad metals.³⁰ By combining the most recent findings in κ -(BEDT-TTF)₂Cu₂(CN)₃^{24,27,30} and compounds with different degree of frustration, ^{5,8,19,20,22,27} in Fig. 1d we present the state-of-the-art phase diagram of Mott systems as a function of T, electronic correlations U/Wand geometrical frustration t'/t.

In this study, we explore the phase space extremely close to the MIT, which requires fine tuning of the correlation strength with a resolution equivalent to 10^{-2} kbar. While such high precision cannot be reached in conventional oil pressure cells,^{21,30} also gas pressure experiments are limited at low temperatures due to solidification of helium.^{23,27} To that end, we utilize strain transmitted through a substrate – a method previously applied in

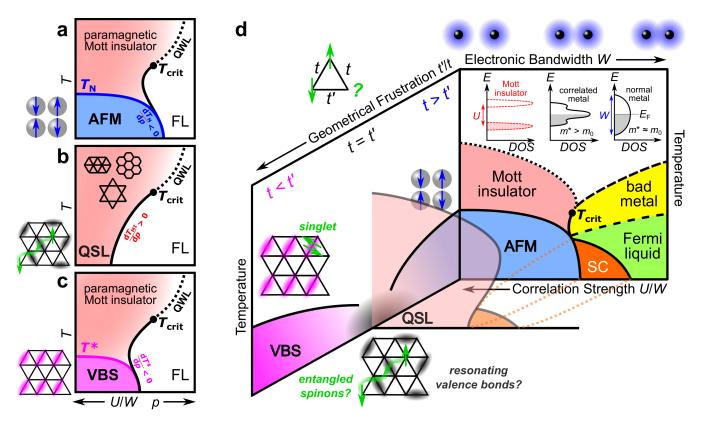


FIG. 1. **a** While the entropy of a paramagnetic Mott insulator exceeds that of the adjacent Fermi liquid (FL), resulting in a positive slope $dT_{\rm MI}/dp > 0$ of the metal-insulator boundary, AFM order has much smaller entropy and the Clausius-Clapeyron relation yields $dT_{\rm N}/dp < 0$, as seen in κ -(BEDT-TTF)₂Cu[N(CN)₂]Cl.^{19,20} **b** No such 'reentrance' of insulating behavior is expected for a *gapless* QSL, possibly realized in triangular, kagome or honeycomb lattices.^{2,3} **c** Similar to AFM, also the transition from a spin-gapped VBS insulator to a metal yields $dT^*/dp < 0$, for instance in EtMe₃P[Pd(dmit)₂]₂.^{5,6} **d** Geometrical frustration t'/t allows to tune the magnetic ground state of *genuine* Mott insulators, causing pronounced changes in the phase diagram affecting also unconventional superconductivity (SC).

doping-tuned experiments.³¹ As sketched in Fig. 2a, a single-crystalline κ -(BEDT-TTF)₂Cu₂(CN)₃ filament of 140 nm thickness is placed on a flexible polyethylene substrate at ambient conditions. Differential thermal expansion between sample and substrate (see Methods) causes an in-plane biaxial compression $\varepsilon_{\text{biaxial}}$ equivalent to 1–2 kbar hydrostatic pressure, which is sufficient to push the sample across the Mott MIT (Fig. 2b). Our dc transport results in Fig. 2c yield metallic properties and an onset of SC below $T_c \approx 4 \text{ K}$ ($\varepsilon_c = 0$, see inset). Note, uniaxial strain experiments on κ -(BEDT-TTF)₂Cu₂(CN)₃ revealed a considerable enhancement of T_c and a broadened SC dome ³² than for isotropic compression. Here, biaxial strain does not affect the in-plane anisotropy and T_c is comparable to hydrostatic pressure experiments.^{21,23}

While differential thermal contraction tunes the sample across the Mott MIT, it does not allow to vary the correlation strength in arbitrary steps. In order to reach back into the Mott state in a quasi-continuous manner, we perform bandwidth-tuning via tensile strain $\varepsilon_c > 0$ along the crystallographic *c*-axis. As indicated on the bottom of Fig. 2a, we control the correlation strength by varying the bending radius of the substrate, which yields a *negative* pressure of less than a kilobar. As such, uniaxial strain is significantly weaker than the overall pressure

applied $(|\varepsilon_c| < |\varepsilon_{\text{biaxial}} + \varepsilon_c|)$, hence we do not expect major effects from a change in frustration t'/t.³² The blue shaded region in Fig. 2b indicates the phase space covered in our experiments with a fixed $\varepsilon_{\text{biaxial}} < 0$ and varying tensile strain between $\varepsilon_c = 0$ and 0.32%. The resulting transport curves in Fig. 2c exhibit a textbook Mott MIT: the resistivity maxima at the Brinkman-Rice temperature $T_{\rm BR}$ are pushed to lower temperatures as correlations increase.^{21,30} In addition, in the range between $\varepsilon_c = 0.17\%$ and 0.25% we observe a distinct upturn of resistance upon cooling well below $T_{\rm BR}$. The resistance minima (magenta arrows in Fig. 2c) shift up to $T^{\star} = 6$ K until metallic behavior is lost completely. Since this phenomenology lines up with the '6K anomaly' at ambient pressure, we identify it as the transition to a spin-gapped nonmetallic state that gets suppressed at the Mott MIT.

The reentrant behavior at low temperatures is apparent not only from a sign change of dR/dT to a nonmetallic slope (dR/dT < 0 below T^*), but can be seen also in the fully insulating curves $\varepsilon_c \ge 0.27\%$. In Fig. 3 we plot the logarithmic derivative $d \ln R/d 1/T$ as a measure of the transport gap $\Delta(T)$. While the gap size is steadily reduced upon cooling from 100 K to 20 K, consistent with the temperature-dependent spectral weight shifts reported in previous optical studies,^{24,30} we observe



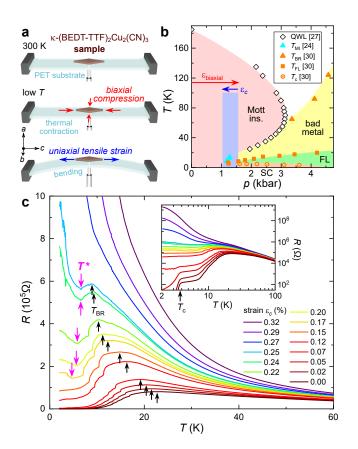


FIG. 2. **a,b** A 140 nm thin single-crystalline filament of κ -(BEDT-TTF)₂Cu₂(CN)₃ was placed on a flexible PET substrate. Cooling from 300 K down to $T \rightarrow 0$ imposes biaxial compression of order 1–2 kbar to the sample due to differential thermal contraction, yielding metallic and superconducting (SC) properties (red arrow in **b**). Uniaxial tensile strain ε_c along the c-axis is applied via bending of the substrate in order to tune from the Fermi liquid (FL) through the Mott MIT (blue arrow in **b**). **b** Crossover and transition temperatures from Refs.,^{23,27,30} as indicated. **c** Resistance of the biaxially compressed crystal for different ε_c . Inset: SC below $T_c \approx 4$ K for $\varepsilon_c = 0$ is evident in the log-log plot. Upon approaching the Mott state, SC is lost and the resistivity maxima at $T_{\rm BR}$ shift to lower temperatures. In addition, our data reveal a reentrance of insulating behavior (magenta arrows) below $T^* < T_{\rm BR}$.

an upturn at low temperatures forming a peak around T^{\star} . For comparison, the VBS transition of EtMe₃- $P[Pd(dmit)_2]_2$ at $T^* = 24$ K yields similar maxima in $d \ln R/d 1/T$ from which we estimate a ratio of gap size and transition temperature $\Delta_{VBS}/(k_BT^{\star}) \approx 5.5$ Assuming the same ratio in the title compound gives $\Delta_{VBS}/k_B \approx 30$ K for $T^{\star} = 6$ K, which compares well with the local maxima in the inset of Fig. 3. In ambientpressure transport studies 24 the regime T < 10 K remained inaccessible due to the extremely large resistance; here, in the vicinity of the MIT R(T) is small enough to be measured. Following its observation in thermodynamic and magnetic probes,^{15,17,25} in our present work we identify the '6K anomaly' in the Mott-insulating state of κ -(BEDT-TTF)₂Cu₂(CN)₃ for the first time in charge transport as a local maximum of $d \ln R/d 1/T$. Even more importantly, we obtain a quantitative estimate of

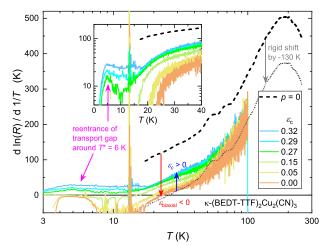


FIG. 3. The transport gap $d \ln R/d 1/T$ determined from the strain-dependent resistance (Fig. 2c) is compared to ambient pressure (black dashed line from Ref.²⁴). While biaxial compression $\varepsilon_{\rm biaxial} < 0$ causes a reduction of the gap size, equivalent to a vertical shift of the p = 0 data by -130 K (grey dotted), the gap increases upon tensile strain $\varepsilon_c > 0$, consistent with the bandwidth tuning in Fig. 2b. The Mott MIT is evident from the sign change at $T_{\rm BR}$. Upon further cooling in the metallic state, $d \ln R/d 1/T \rightarrow 0$ as the residual resistivity is approached, followed by a sharp drop when SC sets in. Notably, the fully insulating curves exhibit a local maximum around $T^{\star} = 6$ K associated with the VBS transition.

the associated energy gap $E_g = 2\Delta \approx 30{-}50$ K at T^* . Note, this significantly exceeds the spin gap of 12 K estimated from ESR data .¹⁵ Crucially, the gap size observed here lines up with the critical field of order 60 T estimated in Ref.¹⁶, which explains why magnetic fields of order 10 T have little effect on the transition.^{17,25}

 $d \ln R/d \ 1/T$ in the range T > 20 K reflects changes of the Mott-Hubbard gap. While the gap size reduces upon biaxial compression, it increases upon uniaxial tension; the negative values below $T_{\rm BR}$ correspond to dR/dT > 0. Interestingly, the strain-induced change upon $\varepsilon_{\rm biaxial} < 0$ is approximately a rigid vertical shift of the ambient-pressure data²⁴ by -130 K (grey dotted line in Fig. 3). Quantitatively, the effect of $\varepsilon_{\rm biaxial}$ is approximately three times bigger than $\varepsilon_c = 0.32\%$, consistent with the red and blue arrows in Fig. 2b, respectively.

In Fig. 4a,b we compare the structural changes at the '6K anomaly' in κ -(BEDT-TTF)₂Cu₂(CN)₃ with the VBS transition at $T^* = 24$ K in EtMe₃P[Pd(dmit)₂]₂.⁴ Thermal expansion experiments by Manna *et al.*^{7,25} revealed very similar anisotropic distortions within the conducting layers at T^* in both quasi 2D organic compounds. As sketched in Fig. 4a,b, the crystal contracts along the *c*-axis and expands along the other in-plane direction upon cooling. Also other probes^{34,35} observed pronounced anomalies at 6 K due to modifications of the crystal structure and possible symmetry breaking, ¹⁶ which are typical fingerprints of a VBS transition. In addition, recent ESR studies revealed a rapid drop of spin susceptibility χ_s due to the opening of a spin gap, ¹⁵ which agrees with NMR Knight shift data from Ref.³³ that yield χ_s indistinguish-

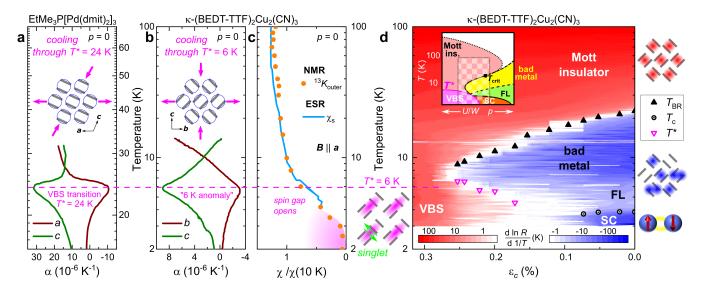


FIG. 4. **a,b** The thermal expansion coefficient α yields similar in-plane anisotropy at the VBS transition of EtMe₃P[Pd(dmit)₂]₂ $(T^* = 24 \text{ K})^7$ and at the '6K anomaly' of κ -(BEDT-TTF)₂Cu₂(CN)₃.²⁵ Note the different scales; data from Refs.^{7,25}. **c** The rapid drop of NMR Knight shift K and ESR susceptibility χ_s (B || a) at $T^* = 6$ K evidences the opening of a spin gap; data from Refs.^{15,33}. **d** The phase diagram of κ -(BEDT-TTF)₂Cu₂(CN)₃ assembled from $R(T, \varepsilon_c)$ (Figs. 2c, 3) is underlaid with a false-color plot of $d \ln R/d 1/T$ (red: insulating, blue: metallic). Inset: checkerboard area indicates range of our strain-dependent experiments. We find a clear back-bending of the insulator-metal boundary (cf. Fig. 1c) originating from the '6K anomaly' at p = 0. Altogether, the ambient pressure data in **b,c** and $dT^*/dp < 0$ in **d** provide solid evidence for a low-entropy spin-singlet phase with structural anisotropy – the hallmarks of a VBS.

able from zero for $T \to 0$, as shown in Fig. 4c.

Altogether, these findings provide solid evidence for anisotropic structural changes at the transition to a singlet state with a gap in the spectrum of spin excitations. In addition, $T^{\star} = 6$ K at p = 0 directly interpolates to the reentrance of the MIT in our strain-dependent transport data, which is mapped in the false-color plot of $d \ln R/d 1/T$ in Fig. 4d. We find that the resulting phase diagram prominently displays $dT^{\star}/dp < 0$ as sketched in Fig. 1c, analogue to the VBS Mott insulator EtMe₃- $P[Pd(dmit)_2]_2^{5,6}$ with similar thermal expansion anomalies (Fig. 4a,b). In light of these overwhelming experimental similarities, we conclude that at ambient pressure the enigmatic '6K anomaly' in κ -(BEDT-TTF)₂- $Cu_2(CN)_3$ is the transition from a paramagnetic Mott insulator to a spin-gapped VBS state. Upon reducing the correlation strength, the VBS phase is suppressed and can be entered from a metallic state upon cooling, as observed here for $0.17\% \leq \varepsilon_c \leq 0.25\%$. As seen in Fig. 4d, the nonmagnetic insulator is adjacent to unconventional SC in the limit $T \rightarrow 0$, suggesting that the '6K anomaly' is relevant for Cooper pair formation.

Since the first reports of the '6K anomaly' and the absence of magnetic order,^{17,26} there have been different interpretations of the experimental results acquired over two decades in independent groups.^{15,18,25,33} Here, we put together now all these pieces and obtain a comprehensive understanding of the low-temperature physics of κ -(BEDT-TTF)₂Cu₂(CN)₃. Our present ultrahighresolution tuning of the '6K anomaly' through the Mott MIT delivers the missing part required to establish it as a true phase transition to a low-entropy spin-singlet ground state with distorted crystal structure. In view of the very shape of the phase diagram presented here, the magnetic, thermal transport, thermodynamic and structural properties of κ -(BEDT-TTF)₂Cu₂(CN)₃^{15,18,25,26,33} are consistent with a spin-gapped VBS state, essentially identical to that reported in other layered organic Mott systems.^{4–8}

As such, we point out that the spin-gapped low-entropy phase associated with the '6K anomaly' is not intrinsic to pure Mott insulators, but rather results from magnetostructural instabilities. Likely, the involved elastic energy contributes to the unexpectedly large gap and critical field, exceeding $k_B T^*/\mu_B \approx 9$ T by far.¹⁶ We suggest that, in absence of the VBS, the metallic state persists much deeper into the insulating region of the phase diagram – in Fig. 2b $T_{\rm FL}$ and $T_{\rm BR}$ extrapolate to zero well below p = 1 kbar.^{23,30} To that end, elucidating the genuine Mott MIT in the limit $T \to 0$ requires to suppress T^{\star} in κ -(BEDT-TTF)₂Cu₂(CN)₃, potentially by varying t'/t through uniaxial strain (Fig. 1d) or by applying high magnetic fields $B \approx 50{-}100$ T. To conclude, our findings highlight the importance to gain understanding and control of magneto-elastic coupling in frustrated spin systems, in particular in other QSL candidates.

METHODS

Sample preparation and application of uniaxial bending strain

We prepared polyethylene terephthalate (PET) substrates (Teflex[®] FT7, Toyobo Film Solutions Limited) and patterned 18-nm-thick Au electrodes using photo-lithography. Thin single crystals of κ -(BEDT-TTF)₂Cu₂(CN)₃ were synthesized with electrolysis of a 1,1,2-trichloroethane [10% (v/v) ethanol] solution (50 ml), in which BEDT-TTF (20 mg), KCN (60mg), CuCN (40 mg), and 18-crown-6 (100 mg) are dissolved. We applied a current of 8 μ A overnight and obtained tiny thin crystals of κ -(BEDT-TTF)₂Cu₂(CN)₃. The crystals were pipetted to 2-propanol, and were manipulated with a tip of hair and put on the substrate. After the substrate was taken out from 2-propanol and dried, the thin crystal tightly adhered to the substrate.

As described in previous work,^{31,36,37} cooling yields differential thermal expansion between sample and substrate: the length change is $\leq 1\%$ between 0 K and 300 K for κ -(BEDT-TTF)₂Cu₂(CN)₃ ^{25,38} compared to $\gg 1\%$ for PET. As a result, the sample is subject to biaxial compression of order 1–2 kbar, deduced from the transport results in Fig. 2 in comparison to previously published resistivity data.^{23,27,30} We applied uniaxial bending strains by pushing the back of the substrate with a nanopositioner (ANPz51, attocube systems) as shown in Fig. 2a. Assuming that the bent substrate is an arc of a circle, the strain S is estimated as $S = 4tx/(l^2 + 4x^2)^{36,37}$ using the small angle approximation, where x is the displacement of the nanopositioner, $t = 177 \mu m$ and l = 12 mm are the thickness and length of the substrate, respectively. The uniaxial tensile strain was applied at 100 K in descending order from 0% to 0.32%. The cooling rate of the sample was 0.5 K/min. The thickness of the studied κ -(BEDT-TTF)₂Cu₂(CN)₃ crystal (140 nm) was measured a *posteriori* using a step profiler. Throughout the manuscript we follow the convention that a reduction of the sample volume (upon compressive stress or pressure) corresponds to negative strain $\varepsilon < 0$, whereas an expansion of the sample size (upon tensile stress or 'negative' pressure) yields $\varepsilon > 0$.

Data Analysis

The QWL in Fig. 2b was taken from Ref.²⁴ whereas $T_{\rm BR}, T_c$ and $T_{\rm FL}$ are from Ref.³⁰ and the insulator-metal boundary below 20 K (cyan) was determined from the resistivity data in Ref.²³. The transport gap of κ -(BEDT- $-TTF)_2Cu_2(CN)_3$ at ambient pressure in Fig. 3 (dashed black line) was taken from Fig. S2 in the Supplementary Information of Ref.²⁴; the grey dotted line is a rigid vertical shift of the ambient-pressure data by -130 K: $\Delta(\varepsilon_{\text{biaxial}}, T) \approx \Delta(p=0,T) - 130$ K. Thermal expansion data in Fig. 4a are from Ref.⁷ and the data in panel b are from Ref.^{25} . The NMR shifts in Fig. 4c were taken from Ref.³³ and the Knight shift K_{outer} was determined for the outer ¹³C nuclei using a chemical shift $\sigma = 117$, as described in Ref.¹⁶ . In the same panel, the ESR susceptibility χ_s for magnetic field perpendicular to the layers $(B \parallel a \text{ similar to the Knight shift data})$ was taken from Fig. 2a in Ref.¹⁵. Both χ_s and K_{outer} were normalized to their value at 10 K.

At elevated temperatures the resistivity maxima indicate $T_{\rm BR}$.³⁰ At lower temperatures in the phase coexistence regime $T \leq T_{crit} \approx 15$ K,³⁹ strictly speaking, the resistivity maxima indicate percolation of metallic regions. We assign the sharp jumps in the resistance data in Fig. 2c, also seen as narrow peaks between 10–15 K in Fig. 3, to an artefact of the sample mounting. As such, the apparent strain dependence is naturally related to the volume change of the sample that interferes with the applied strain. A micro-crack will open or close for a particular differential thermal expansion between sample and substrate, reached at a different temperature for different strain conditions upon changing ε_c .

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